



Micro Commercial Components
20736 Marilla Street Chatsworth
CA 91311
Phone: (818) 701-4933
Fax: (818) 701-4939

BAS40 THRU BAS70

Features

- SOT-23 Package For surface mount application
- Protects from line to V_{CC} and line to ground
- Low forward voltage and reverse recovery characteristics
- Bidirectional-low-forward available with “-04” suffix (Figure 2)
- Tape & Reel EIA Standard 481.

Mechanical Data

- Molded: SOT-23 Surface Mount
- Body marked with device number.
- Mounting Position: Any
- Weight: .008 grams (approx.)

MAXIMUM RATINGS

- Operating Temperature: -55°C to $+125^{\circ}\text{C}$
- Storage Temperature: -55°C to $+150^{\circ}\text{C}$
- Power Dissipation: 200 mWatts @ $T_{\text{amb}}=25^{\circ}\text{C}$
- Forward Continuous Current: 200mA @ $T_{\text{amb}}=25^{\circ}\text{C}$
- Surge Forward Current: 600mA @ $t_p<1\text{s}$, $T_{\text{amb}}=25^{\circ}\text{C}$

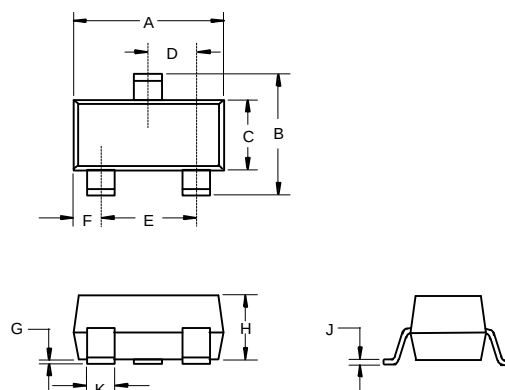
DESCRIPTION

Various configurations of Schottky barrier's diodes in SOT-23 package are provided for general-purpose use in high-speed switching ,mixers and detector applications. They may also be used for signal integrity and counteract the transmission-line effects with (PC) board trances by clamping over/and undershoot from signal reflections with the schottky-low-threshold voltages.

This type of termination also does not depend on matching the transmission line characteristic impedance, making it particularly useful where line impedance is unknown or a variable. This method of termination can control distortions of clock, data, address, and control lines as well as provides a stabilizing effect on signal jitter. It can also significantly reduce power consumption compared to standard resistor-based termination methods.

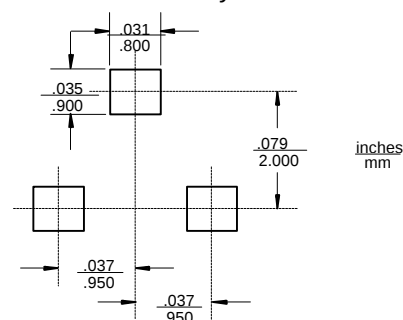
Surface Mount Schottky Barrier Diode 200 mWatt

SOT-23



DIM	INCHES		MM		NOTE
	MIN	MAX	MIN	MAX	
A	.110	.120	2.80	3.04	
B	.083	.098	2.10	2.64	
C	.047	.055	1.20	1.40	
D	.035	.041	.89	1.03	
E	.070	.081	1.78	2.05	
F	.018	.024	.45	.60	
G	.0005	.0039	.013	.100	
H	.035	.044	.89	1.12	
J	.003	.007	.085	.180	
K	.015	.020	.37	.51	

Suggested Solder Pad Layout



BAS40 and BAS70

ELECTRICAL CHARACTERISTICS PER DIODE @ 25°C Unless otherwise specified

DEVICE TYPE	DEVICE MARKING	FIGURE	Repetitive Peak Reverse Voltage	Reverse Breakdown Voltage Tested with 10µA Pulse	Leakage Current Pulse test tp < 300µs @		Forward Voltage Pulse Test tp < 300µs at I _F = 1 mA at I _F = 40 mA			Reverse Recovery Time from I _F = 10 mA through I _R =10mA to I _R =1mA	Thermal Resistance Junction to Ambient Air	Capacitance At V _R = 0V F = 1 MHz C _{tot}
			V _{RRM} (VOLTS)	V _{(BR)R} (VOLTS)	I _R (nA)		V _F (mV)			t _{rr} (ns)	R _{thJA} (K/W)	pF
			TYP	MIN	TYP	MAX	I _F =1mA	I _F =15mA	I _F =40mA	MAX	MAX	MAX
BAS40	43	1	40	40	20	200	380		1000	5	430	5
BAS40-04	44	2	40	40	20	200	380		1000	5	430	5
BAS40-05	45	3	40	40	20	200	380		1000	5	430	5
BAS40-06	46	4	40	40	20	200	380		1000	5	430	5
BAS70	73	1	70	70	20	200	410	1000		5	430	2
BAS70-04	74	2	70	70	20	200	410	1000		5	430	2
BAS70-05	75	3	70	70	20	200	410	1000		5	430	2
BAS70-06	76	4	70	70	20	200	410	1000		5	430	2

